NST856BF3T5G

PNP General Purpose Transistor

The NST856BF3T5G device is a spin-off of our popular SOT-23/SOT-323/SOT-563/SOT-963 three-leaded device. It is designed for general purpose amplifier applications and is housed in the SOT-1123 surface mount package. This device is ideal for low-power surface mount applications where board space is at a premium.

Features

- h_{FE}, 220–475
- Low $V_{CE(sat)}$, $\leq -0.3 V$
- Reduces Board Space
- This is a Halide–Free Device
- This is a Pb–Free Device

MAXIMUM RATINGS

Rating	Symbol	Value	Unit		
Collector – Emitter Voltage	V _{CEO}	-65	Vdc		
Collector – Base Voltage	V _{CBO}	-80	Vdc		
Emitter – Base Voltage	V _{EBO}	-5.0	Vdc		
Collector Current – Continuous	Ic	-100	mAdc		
THERMAL CHARACTERISTICS					
Characteristic	Symbol	Max	Unit		
Total Device Dissipation, T _A = 25°C Derate above 25°C	P _D (Note 1)	290 2.3	mW mW/°C		
Thermal Resistance, Junction-to-Ambient	R _{θJA} (Note 1)	432	°C/W		
Total Device Dissipation, T _A = 25°C Derate above 25°C	P _D (Note 2)	347 2.8	mW mW/°C		
Thermal Resistance, Junction-to-Ambient	R _{θJA} (Note 2)	360	°C/W		
Thermal Resistance, Junction-to-Lead 3	R _{ΨJL} (Note 2)	143	°C/W		
Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C		

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

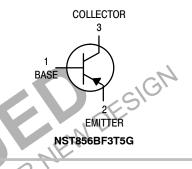
1. 100 mm² 1 oz, copper traces.

2. 500 mm² 1 oz, copper traces.



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MARKING DIAGRAM





ORDERING INFORMATION

Devid	e	Package	Shipping [†]
NST856BF	3T5G	SOT-1123 (Pb-Free)	8000/Tape & Reel

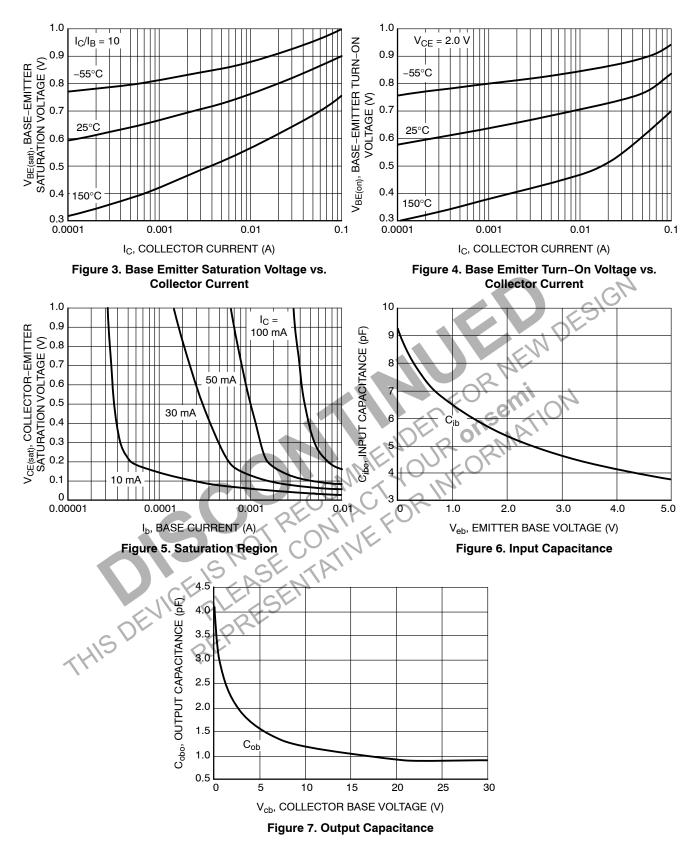
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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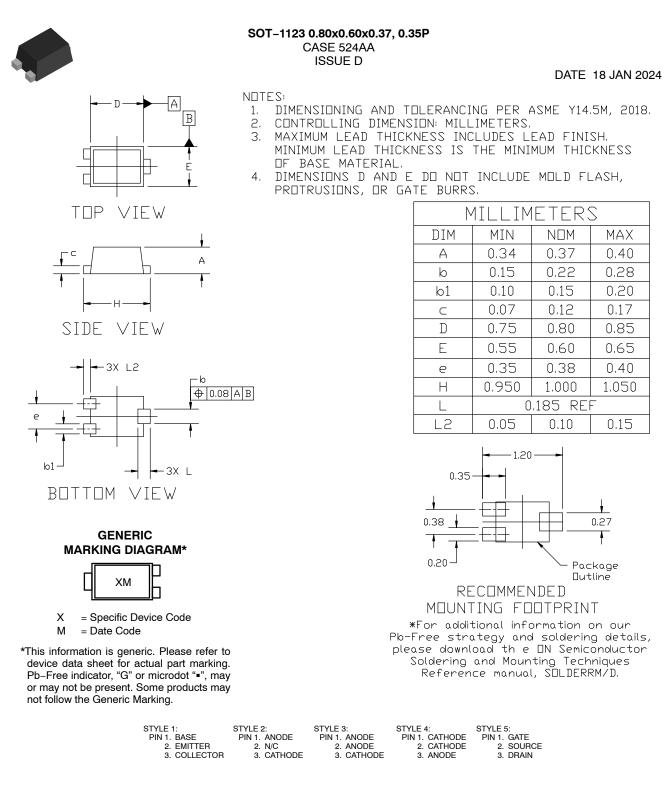
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (I _C = –10 mA)	V _{(BR)CEO}	-65	-	-	V
Collector – Emitter Breakdown Voltage (I _C = –10 μ A, V _{EB} = 0)	V _{(BR)CES}	-80	-	-	V
Collector – Base Breakdown Voltage (I _C = $-10 \ \mu$ A)	V _{(BR)CBO}	-80	-	-	V
Emitter – Base Breakdown Voltage ($I_E = -1.0 \ \mu A$)	V _{(BR)EBO}	-5.0	-	-	V
Collector Cutoff Current (V _{CB} = -30 V) (V _{CB} = -30 V, T _A = 150° C)	I _{CBO}	_ _	- -	-15 -4.0	nA μA
ON CHARACTERISTICS			-		
DC Current Gain (I _C = -10 μ A, V _{CE} = -5.0 V) (I _C = -2.0 mA, V _{CE} = -5.0 V)	h _{FE}	_ 220	150 290	_ 475	_
Collector – Emitter Saturation Voltage ($I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA}$) ($I_C = -100 \text{ mA}, I_B = -5.0 \text{ mA}$)	V _{CE(sat)}	-	-	-0.3 -0.8	V
Base – Emitter Saturation Voltage ($I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA}$) ($I_C = -100 \text{ mA}, I_B = -5.0 \text{ mA}$)	V _{BE(sat)}	-	-0.7 -0.9		V
Base – Emitter On Voltage $(I_C = -2.0 \text{ mA}, V_{CE} = -5.0 \text{ V})$ $(I_C = -10 \text{ mA}, V_{CE} = -5.0 \text{ V})$	V _{BE(on)}	-0.6 -	ni <u>-</u> n	-0.75 -0.82	V
SMALL-SIGNAL CHARACTERISTICS	· 20 '	~SE.	10.		
Current – Gain – Bandwidth Product ($I_C = -10$ mA, $V_{CE} = -5.0$ Vdc, f = 100 MHz)	NDAR	100	<u>`-</u>	-	MH
Output Capacitance (V _{CB} = -10 V, f = 1.0 MHz)	Cobo	01	-	4.5	pF
Input Capacitance ($V_{EB} = -0.5 \text{ V}$, $I_C = 0 \text{ mA}$, f = 1.0 MHz)	Cibo	-	-	10	pF
Noise Figure (I _C = -0.2 mA, V _{CE} = -5.0 Vdc, R _S = 2.0 kΩ, f = 1.0 kHz, BW = 200 Hz)	NF	_	-	10	dB
$ \begin{array}{c} 0.16 \\ 0.12 \\ 0.12 \\ 0.02 \\ 0.0001 \\ 0.001 \\ 0.01 $	25°C (1.0 V -55°C (5.0 V 200 -55°C (1.0 V -55°C (1.0 V 0 0 0.0001	0.001		2.01	
I _C , COLLECTOR CURRENT (A)		_C , COLLECT			urron
Figure 1. Collector Emitter Saturation Voltage vs. Collector Current	Figure 2. D	Current	Gain vs. C	ollector C	urren

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DESCRIPTION:	SOT-1123 0.80x0.60x0.37, 0.35P		PAGE 1 OF 1

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